

## DESCRIPTION

The HX3400S uses advanced trench technology to provide excellent  $R_{DS(ON)}$ , low gate charge and high density cell Design for ultra low on-resistance. This device is suitable for use as a load switch or in PWM applications.

## GENERAL FEATURES

- ◊  $V_{DS} = 30V$ ,  $I_D = 5.8A$   
 $R_{DS(ON)}(\text{Typ.}) = 30m\Omega$  @  $V_{GS} = 2.5V$   
 $R_{DS(ON)}(\text{Typ.}) = 24m\Omega$  @  $V_{GS} = 4.5V$
- ◊ High power and current handing capability
- ◊ Lead free product is acquired
- ◊ Surface mount package

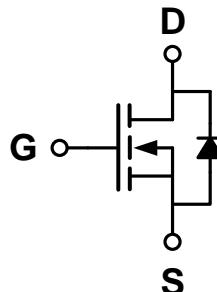
## APPLICATION

- ◊ PWM applications
- ◊ Load switch

## PACKAGE

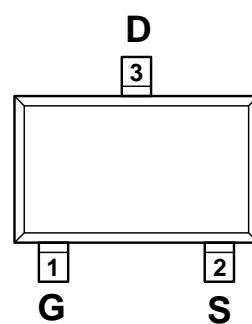
- ◊ SOT-23

## SCHEMATIC DIAGRAM



## PIN ASSIGNMENT

SOT-23  
(TOP VIEW)



## ORDERING INFORMATION

| Part Number | Storage Temperature | Package | Marking | Devices Per Reel |
|-------------|---------------------|---------|---------|------------------|
| HX3400S     | -55°C to +150°C     | SOT-23  | A09T.   | 3000             |

NOTE: HX2300S : S It stands for SOT-23

## ABSOLUTE MAXIMUM RATINGS

( $T_A=25^\circ C$  unless otherwise noted)

| parameter   | symbol                       | limit    | unit |
|---|------------------------------|----------|------|
| Drain-source voltage  | $V_{DS}$                     | 30       | V    |
| Gate-source voltage   | $V_{GS}$                     | $\pm 12$ | V    |
| Continuous drain current ( $T_J = 150^\circ C$ ) <sup>a</sup> | $I_D$ ( $T_A = 25^\circ C$ ) | 5.8      | A    |
|   | $I_D$ ( $T_A = 70^\circ C$ ) | 5        |      |
| Pulsed drain current <sup>b</sup>                             | $I_{DM}$                     | 23.2     |      |
| Continuous source current (diode conduction) <sup>a</sup>     | $I_S$                        | 0.6      |      |
| Power dissipation <sup>a</sup>                                | $T_A = 25^\circ C$           | 0.71     | W    |
|   | $T_A = 70^\circ C$           | 0.46     |      |
| Operating junction and storage temperature range              | $T_J, T_{stg}$               | -55—150  | °C   |

## THERMAL CHARACTERISTICS

| Parameter                                | Symbol          | Typ | Max | Unit |
|--|-----------------|-----|-----|------|
| Maximum junction-to-ambient <sup>a</sup> | $R_{\theta JA}$ | 120 | 145 | °C/W |
| Steady-State                             |                 | 140 | 175 |      |
| Maximum junction-to-foot                 | $R_{\theta JC}$ | 62  | 78  |      |

### Notes

- a. Surface mounted on 1" x 1" FR4 board
- b. Pulse width limited by maximum junction temperature

## ELECTRICAL CHARACTERISTICS ( $T_A=25^\circ C$ unless otherwise noted)

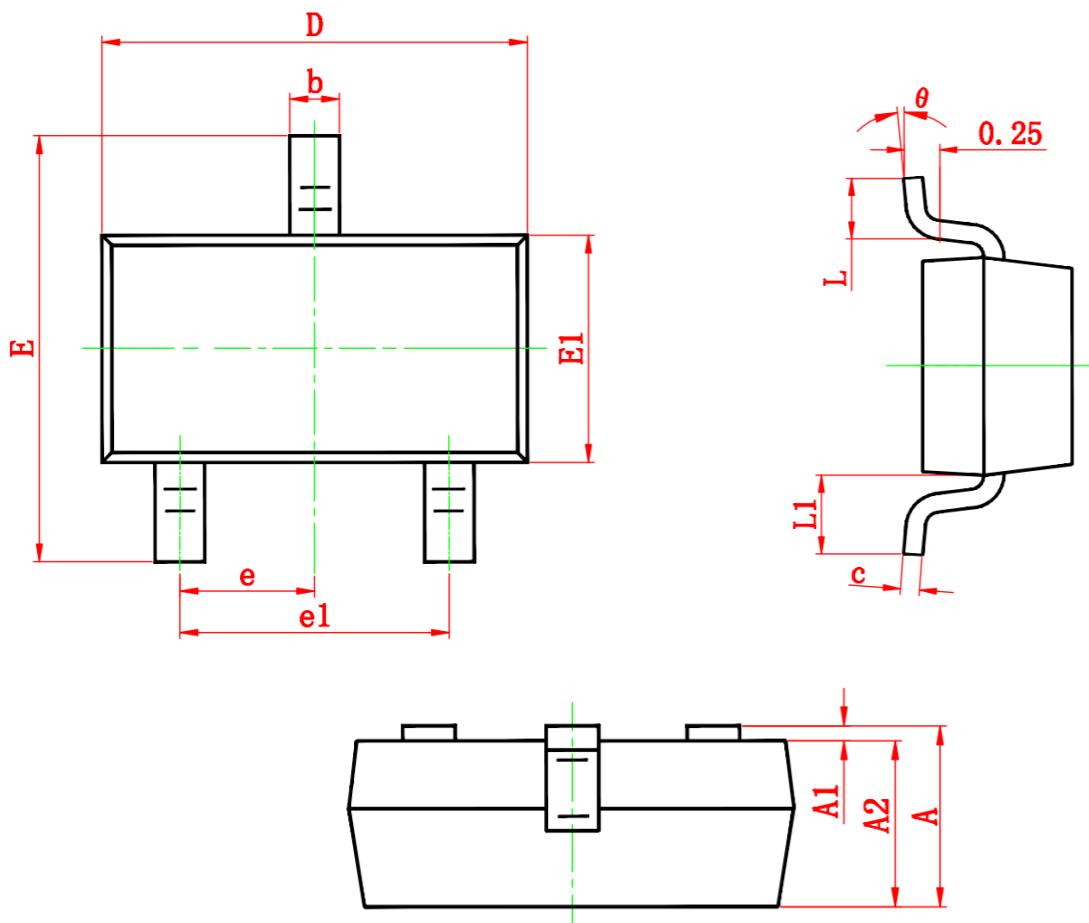
| Parameter                                     | Symbol       | Condition   | Min | Typ  | Max       | Unit      |
|---|--------------|---|-----|------|-----------|-----------|
| <b>OFF Characteristics</b>                    |              |   |     |      |           |           |
| Drain-source breakdown voltage                | $BV_{DSS}$   | $V_{GS}=0V, I_D=250\mu A$   | 30  | -    | -         | V         |
| Zero gate voltage drain current               | $I_{DSS}$    | $V_{DS}=30V, V_{GS}=0V$   | -   | -    | 1         | $\mu A$   |
| Gate-body leakage                             | $I_{GSS}$    | $V_{DS}=0V, V_{GS}=\pm 12V$   | -   | -    | $\pm 100$ | nA        |
| <b>ON Characteristics</b>                     |              |   |     |      |           |           |
| Gate threshold voltage                        | $V_{GS(th)}$ | $V_{DS}=V_{GS}, I_D=250\mu A$   | 0.5 | 0.9  | 1.5       | V         |
| Drain-source on-state resistance <sup>a</sup> | $R_{DS(ON)}$ | $V_{GS}=4.5V, I_D=5A$   | -   | 24   | 30        | $m\Omega$ |
|   |              | $V_{GS}=2.5V, I_D=4A$   | -   | 30   | 45        |           |
| Forward transconductance <sup>a</sup>         | $g_{fs}$     | $V_{DS}=5V, I_D=5.8A$   | -   | 33   | -         | S         |
| <b>Dynamic Characteristics <sup>b</sup></b>   |              |   |     |      |           |           |
| Input capacitance                             | $C_{iss}$    | $V_{DS}=15V, V_{GS}=0V$<br>$f=1.0MHz$   | -   | 630  | -         | pF        |
| Output capacitance                            | $C_{oss}$    |   | -   | 76   | -         |           |
| Reverse transfer capacitance                  | $C_{rss}$    |   | -   | 55   | -         |           |
| <b>Switching Characteristics</b>              |              |   |     |      |           |           |
| Turn-on delay time                            | $t_{D(ON)}$  | $V_{DS}=15V$<br>$V_{GS}=10V$<br>$R_L=2.6\text{ ohm}$<br>$R_{GEN}=3\text{ohm}$ | -   | 3    | -         | ns        |
| Rise time                                     | $t_r$        |   | -   | 2.5  | -         |           |
| Turn-off delay time                           | $t_{D(OFF)}$ |   | -   | 25   | -         |           |
| Fall time                                     | $t_f$        |   | -   | 4    | -         |           |
| Total gate charge                             | $Q_g$        | $V_{DS}=15V, I_D=5.8A$<br>$V_{GS}=4.5V$                                       | -   | 6    | -         | nC        |
| Gate-source charge                            | $Q_{gs}$     |   | -   | 1.3  | -         |           |
| Gate-drain charge                             | $Q_{gd}$     |   | -   | 1.8  | -         |           |
| <b>DRAIN-SOURCE DIODE CHARACTERISTICS</b>     |              |   |     |      |           |           |
| Diode forward voltage                         | $V_{SD}$     | $V_{GS}=0V, I_s=1A$   | -   | 0.72 | 1.2       | V         |

### Notes

- a. Pulse test: Pulse width  $\leq 300\ \mu s$ , duty cycle  $\leq 2\%$
- b. Guaranteed by design, not subject to production testing

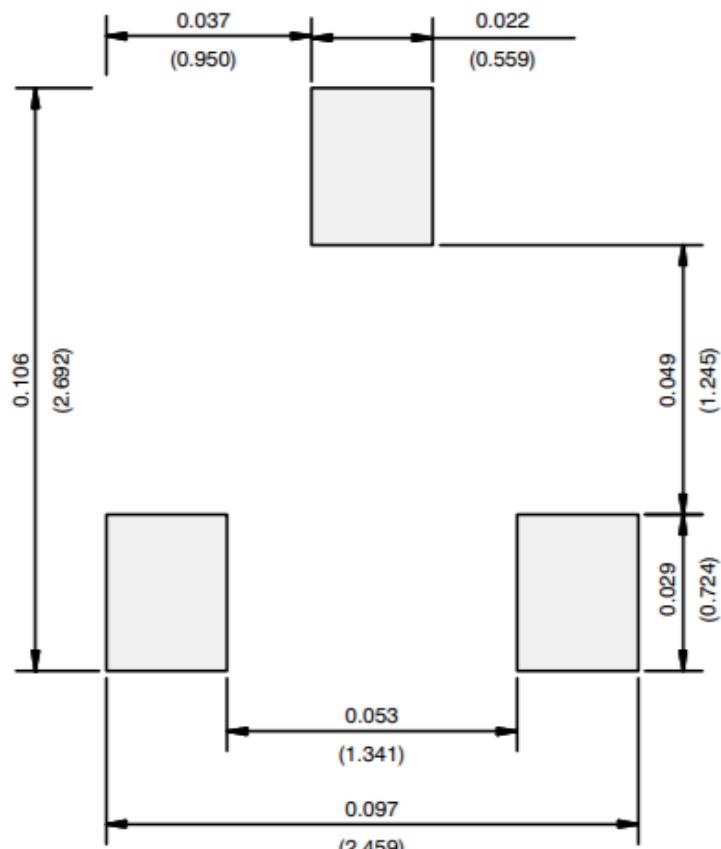
**PACKAGE INFORMATION**

## ● SOT-23



| Symbol | Dimensions In Millimeters |       | Dimensions In Inches |       |
|--------|---------------------------|-------|----------------------|-------|
|        | Min.                      | Max.  | Min.                 | Max.  |
| A      | 0.900                     | 1.150 | 0.035                | 0.045 |
| A1     | 0.000                     | 0.100 | 0.000                | 0.004 |
| A2     | 0.900                     | 1.050 | 0.035                | 0.041 |
| b      | 0.300                     | 0.500 | 0.012                | 0.020 |
| c      | 0.080                     | 0.150 | 0.003                | 0.006 |
| D      | 2.800                     | 3.000 | 0.110                | 0.118 |
| E      | 2.250                     | 2.550 | 0.089                | 0.100 |
| E1     | 1.200                     | 1.400 | 0.047                | 0.055 |
| e      | 0.950 TYP.                |       | 0.037 TYP.           |       |
| e1     | 1.800                     | 2.000 | 0.071                | 0.079 |
| L      | 0.300                     | 0.500 | 0.012                | 0.020 |
| L1     | 0.550 REF.                |       | 0.022 REF.           |       |
| θ      | 0°                        | 8°    | 0°                   | 8°    |

**RECOMMENDED MINIMUM PADS FOR SOT-23**



Recommended Minimum Pads  
Dimensions in Inches/(mm)